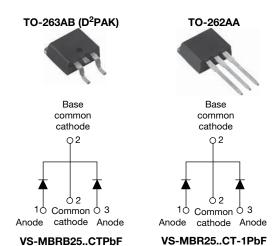


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High Performance Schottky Rectifier, 2 x 15 A



PRODUCT SUMMARY	
Package	TO-263AB (D ² PAK), TO-262AA
I _{F(AV)}	30 A
V_R	35 V, 45 V
V _F at I _F	0.73 V
I _{RM} max.	40 mA at 125 °C
T _J max.	150 °C
Diode variation	Common cathode
E _{AS}	16 mJ

FEATURES

- 150 °C T_{.1} operation
- Center tap D²PAK and TO-262 packages
- · Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



COMPLIANT HALOGEN FREE

- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform (per device)	30	۸			
I _{FRM}	T _C = 130 °C (per leg)	30	A			
V_{RRM}		35, 45	V			
I _{FSM}	t _p = 5 μs sine	1060	А			
V _F	30 A _{pk} , T _J = 125 °C	0.73	V			
TJ	Range	-65 to +150	°C			

VOLTAGE RATINGS						
PARAMETER SYMBOL VS-MBRB2535CTPbF VS-MBRB2545CTPbF VS-MBR2545CT-1PbF VS-MBR2545CT-1PbF UNITS						
Maximum DC reverse voltage	V_R	35	45	V		
Maximum working peak reverse voltage	V_{RWM}	33	45	V		

ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average	per leg	_	$T_C = 130 ^{\circ}\text{C}$, rated V_B		15	
forward current	per device	I _{F(AV)}	TC = 130 C, rated V _R	$T_C = 130^{\circ}$ C, rated V_R		
Peak repetitive forward current per leg		I_{FRM}	Rated V _R , square wave, 20 kHz, T _C = 130 °C		30	
Non-repetitive peak surge cur	Non-repetitive peak surge current		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	1060	Α
, , ,			Surge applied at rated load conditions half wave, single phase, 60 Hz		150	
Non-repetitive avalanche ene	rgy per leg	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 2 \text{A}, L = 8 \text{mH}$		16	mJ
Repetitive avalanche current p	per leg	I _{AR}	Current decaying linear Frequency limited by T	rly to zero in 1 μs _J maximum V _A = 1.5 x V _R typical	2	Α

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS	
Maximum forward voltage drop	V _{FM} ⁽¹⁾	30 A	T _J = 25 °C	0.82	V	
waxiinum forward voitage drop	V FM (1)	30 A	T _J = 125 °C	0.73	V	
Maximum instantaneous reverse current	I _{RM} ⁽¹⁾	T _J = 25 °C	Rated DC voltage	0.2	mA	
		T _J = 125 °C	hated DC voltage	40		
Threshold voltage	V _{F(TO)}	$T_{.1} = T_{.1}$ maximum		0.355	V	
Forward slope resistance	r _t	ij = ij maximum		12.3	mΩ	
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal ran	ge 100 kHz to 1 MHz), 25 °C	700	pF	
Typical series inductance	L _S	Measured from top of ten	8.0	nH		
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs	

Note

 $^{^{(1)}\,}$ Pulse width $<300~\mu s,$ duty cycle <2~%

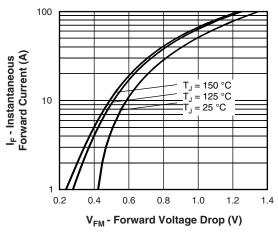
THERMAL - MECHA	THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	OL TEST CONDITIONS		UNITS	
Maximum junction tempera	ture range	TJ		-65 to +150	°C	
Maximum storage tempera	ture range	T _{Stg}		-65 to +175		
Maximum thermal resistance, junction to case per leg		R _{thJC}	DC operation	1.5	20044	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	°C/W	
Approximate weight				2	g	
Approximate weight				0.07	OZ.	
Mounting torque	minimum		Non-lubricated threads	6 (5)	kgf · cm	
maximum			Non-lubricated threads	12 (10)	(lbf · in)	
Marking device			Case style D ² PAK	MBRB2	2545CT	
			Case style TO-262	MBR25	45CT-1	

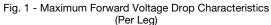




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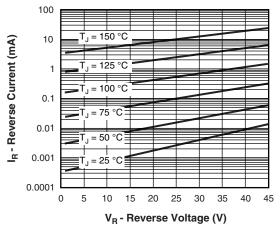


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

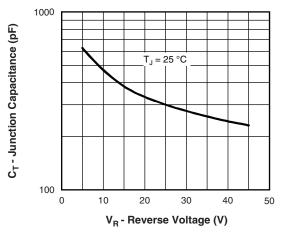


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

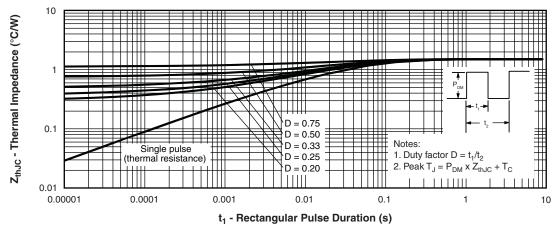


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)



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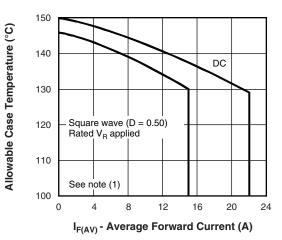


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

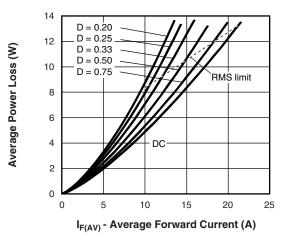
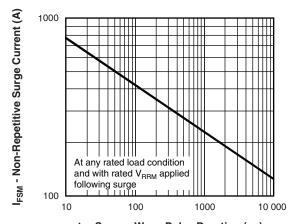


Fig. 6 - Forward Power Loss Characteristics (Per Leg)



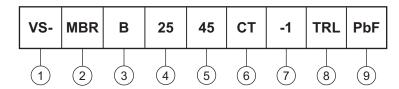
 t_p - Square Wave Pulse Duration (μ s) Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

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ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- 2 Essential part number
- 3 • B = D²PAK 7 None
 - None = TO-262 7 = -1
- Current rating (25 = 25 A)
- 5 Voltage ratings 35 = 35 V 45 = 45 V
- 6 CT = essential part number
- 7 • None = D²PAK 3 = B • -1 = TO-262 3 Non
- -1 = TO-262 3 None • None = tube (50 pieces)
 - TRL = tape and reel (left oriented for D²PAK only)
 - TRR = tape and reel (right oriented for D²PAK only)
- 9 • PbF = lead (Pb)-free (for TO-262 and D²PAK tube)
 - P = lead (Pb)-free (for D²PAK TRR and TRL)

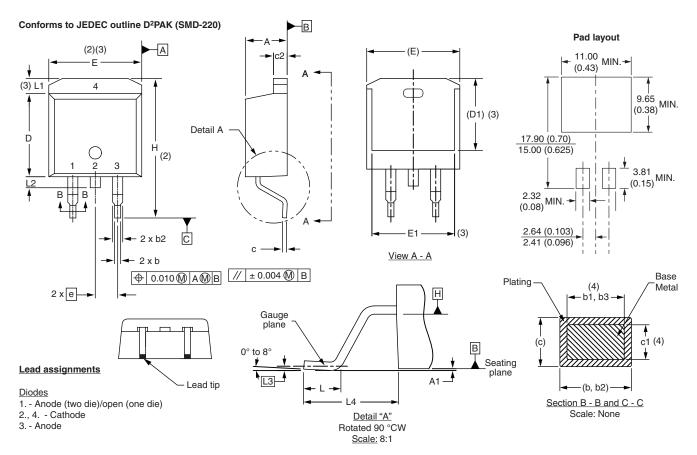
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95014			
Part marking information	www.vishay.com/doc?95008			
Packaging information	www.vishay.com/doc?95032			



Vishay Semiconductors

D²PAK, TO-262

DIMENSIONS - D²PAK in millimeters and inches



	1		1		
SYMBOL	MILLIMETERS		INC	NOTES	
	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}\,$ Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch

(7) Outline conforms to JEDEC outline TO-263AB

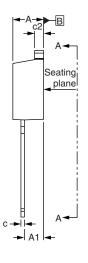
Document Number: 95014 Revision: 31-Mar-09

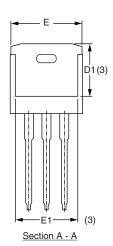
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D²PAK, TO-262



DIMENSIONS - TO-262 in millimeters and inches





⊕ 0.010 **M** A **M** B

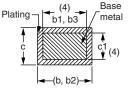
Lead assignments



Diodes

1. - Anode (two die)/open (one die) 2., 4. - Cathode

3. - Anode



Section B - B and C - C Scale: None

SYMBOL	MILLIM	MILLIMETERS		INCHES		
	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		
A1	2.03	3.02	0.080	0.119		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	
D1	6.86	8.00	0.270	0.315	3	
Е	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
е	2.54 BSC		0.100	D BSC		
L	13.46	14.10	0.530	0.555		
L1	=	1.65	-	0.065	3	
L2	3.56	3.71	0.140	0.146		

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline

Legal Disclaimer Notice



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